SMD Type

ZX7365

600mA, LOW QUIESCENT CURRENT FAST TRANSIENT LOW DROPOUT LINEAR REGULATOR

Description

The ZX7365 is a 600mA, adjustable and fixed output voltage, low dropout linear regulator. This device includes pass element, error amplifier, band-gap, current limit and thermal shutdown circuitry. The device is turned on when EN pin is set to logic high level.

The characteristics of low dropout voltage and low quiescent current make it suitable for low power applications such as battery powered devices. The typical quiescent current is approximately 35 μ A. Built-in current-limit and thermal-shutdown functions prevent IC from damage in fault conditions.

This device is available with adjustable output from 0.8V to 5.0V, and fixed version with 0.8V, 1.0V, 1.2V, 1.5V, 1.8V, 2.0V, 2.5V, 2.8V, 3.0V, 3.3V and 3.9V outputs. Please contact your local sales office for other voltage options.

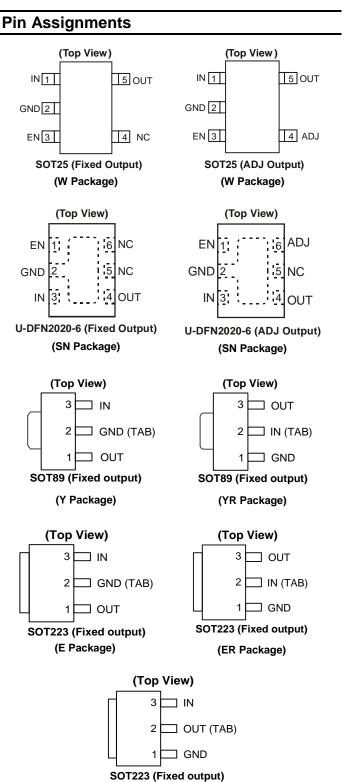
The ZX7365 is available in SOT25, SOT89, SOT223, and U DFN2020-6 packages.

Features

- 600mA Low Dropout Regulator with EN
- Very low IQ: 35µA
- Wide Input Voltage Range: 2V to 6V
- Wide Adjustable Output: 0.8V to 5.0V
- Fixed Output Options: 0.8V to 3.9V (0.1V Step Size Possible)
- High PSRR: 65dB at 1kHz
- Fast Start-Up Time: 200µs
- Stable with Low ESR, 1µF Ceramic Output Capacitor
- Excellent Load/Line Transient Response
- Low Dropout: 300mV at 600mA
- Current Limit and Short Circuit Protection
- Thermal Shutdown Protection
- Ambient Temperature Range: -40°C to +85°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

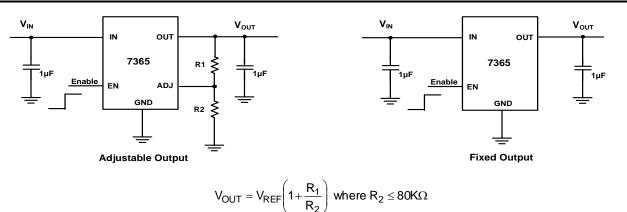
- Servers and Notebook Computers
- Low and Medium Power Applications
- FPGA and DSP Core or I/O Power
- Consumer Electronics



(EV Package)



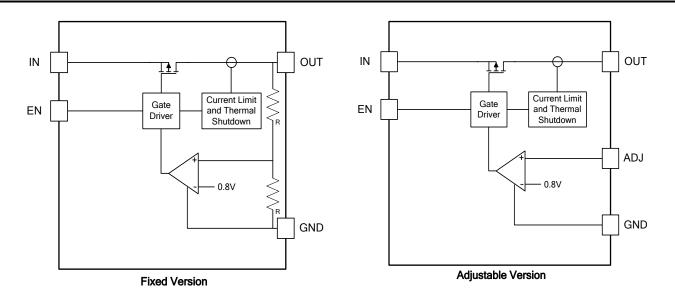
Typical Applications Circuit



Pin Descriptions

		Pin Number						
Pin Name	SOT25 (Fixed)	SOT25 (ADJ)	U-DFN2020-6 (Fixed)	U-DFN2020-6 (ADJ)	SOT223	SOT89 (YR Package) SOT223 (ER Package)	(EV Package)	Functions
IN	1	1	3	3	3	2	3	Voltage Input Pin. Bypass to ground through at least 1µF MLCC capacitor
GND	2	2	2	2	2	1	1	Ground
EN	3	3	1	1	—	_	_	Enable Input, Active High
ADJ	_	4	—	6	—	_	_	Output Feedback Pin
NC	4	_	5, 6	5	—	_	_	No Connection
OUT	5	5	4	4	1	3	2	Voltage Output Pin. Bypass to ground through 1µF MLCC capacitor

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Ratings	Unit
ESD HBM	Human Body Model ESD Protection	2000	V
ESD MM	Machine Model ESD Protection	200	V
V _{IN}	Input Voltage	6.5	V
	OUT, EN Voltage	V _{IN} +0.3	V
—	Continuous Load Current per Channel	Internal Limited	—
T _{ST}	Storage Temperature Range	-65 to +150	°C
TJ	Maximum Junction Temperature	+150	۵°

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Мах	Unit
V _{IN}	Input Voltage	2	6	V
lout	Output Current (Note 4)	0	600	mA
T _A	Operating Ambient Temperature	-40	+85	°C

Note: 4. The device maintains a stable, regulated output voltage without a load current.

Electrical Characteristics (@T_A = +25°C, $V_{IN} = V_{OUT}$ +1V, $C_{OUT} = 1\mu$ F, $C_{IN} = 1\mu$ F, $V_{EN} = 2V$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{REF}	ADJ Reference Voltage (Adjustable Version)	I _{OUT} = 0mA	—	0.8	-	V
I _{ADJ}	ADJ Leakage (Adjustable Version)	—	—	0.1	1.0	μA
Vout	Output Voltage Accuracy	$T_A = -40^{\circ}C$ to $+85^{\circ}C$, lout = 10% of lout-Max	-2	_	+2	%
ΔV _{OUT} /ΔV _{IN} /V	Line Regulation	$V_{IN} = (V_{OUT} + 1V)$ to V_{IN-Max} , $V_{EN} = V_{IN}$, $I_{OUT} = 1mA$	_	0.02	0.20	%/V
$\Delta V_{OUT}/V_{OUT}$	Load Regulation	$V_{IN} = (V_{OUT} + 1V)$ to V_{IN-Max} , $I_{OUT} = 1$ mA to 600mA	-1.0	_	+1.0	%
		V _{OUT} < 2.5V, I _{OUT} = 600mA	_	370	600	
Vdropout	Dropout Voltage (Note 5)	V _{OUT} ≥ 2.5V, I _{OUT} = 600mA	_	300	400	mV
lq	Input Quiescent Current	$V_{EN} = V_{IN}, I_{OUT} = 0mA$	—	35	80	μA
ISHDN	Input Shutdown Current	$V_{EN} = 0V, I_{OUT} = 0mA$	—	0.1	1.0	μA
I _{LEAK}	Input Leakage Current	V _{EN} = 0V, OUT grounded	—	0.1	1.0	μA
t _{ST}	Start-Up Time	V _{EN} = 0V to 2.0V in 1µs, I _{OUT} = 600mA	_	200	_	μs
PSRR	PSRR (Note 6)	$V_{IN} = [V_{OUT} + 1V] V_{DC} + 0.5V_{ppAC},$ f = 1kHz, I _{OUT} = 50mA	_	65	_	dB
I _{SHORT}	Short-Circuit Current	$V_{IN} = V_{IN-Min}$ to V_{IN-Max} , $V_{OUT} < 0.2V$ (fixed version) or 25% of V_{OUT} (ADJ version)	_	240		mA
ILIMIT	Current limit	V _{IN} = V _{IN-Min} to V _{IN-Max} , V _{OUT} /R _{OUT} = 2.5A	0.8	1.4		А
VIL	EN Input Logic Low Voltage	$V_{IN} = V_{IN-Min}$ to V_{IN-Max}	_	—	0.4	V
VIH	EN Input Logic High Voltage	$V_{IN} = V_{IN-Min}$ to V_{IN-Max}	1.4	—	—	V
I _{EN}	EN Input Current	$V_{IN} = 0V \text{ or } V_{IN-Max}$	-1	—	+1	μA
T _{SHDN}	Thermal Shutdown Threshold		—	+145	_	°C
T _{HYS}	Thermal Shutdown Hysteresis	—	_	+15	_	°C

Notes: 5. Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value. This parameter only applies to input voltages above minimum $V_{IN} = 2.0V$.

6. At V_{IN} < 2.3V, the PSRR performance may be reduced.

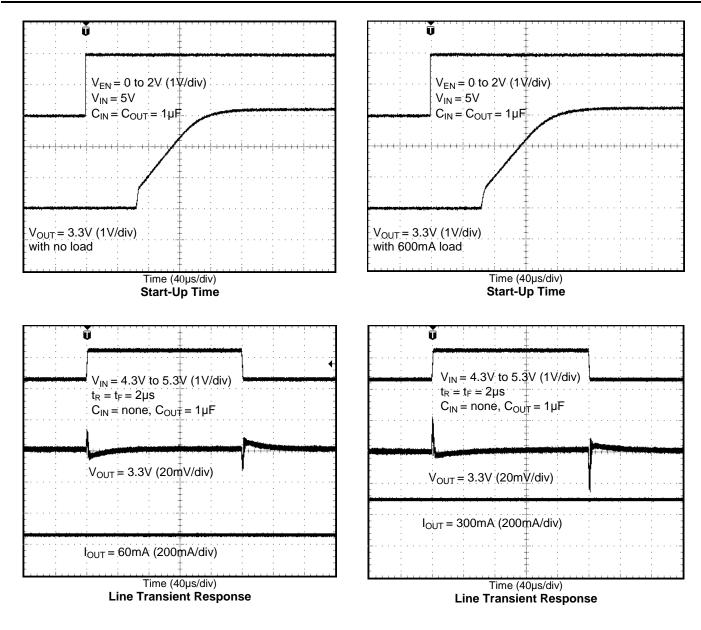


Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
		SOT25 (Note 7)	—	169	—	
0	Thermal Desistence, lunction to Ambient	U-DFN2020-6 (Note 7)	_	132	_	°C/W
θja	Thermal Resistance Junction-to-Ambient	SOT89 (Note 7)	_	133	_	-0/00
		SOT223 (Note 7)	_	142	_	
		SOT25 (Note 7)	—	31	—	
0	Thermal Desistance, lunction to Coos	U-DFN2020-6 (Note 7)	_	48	—	0000
θ_{JC}	Thermal Resistance Junction-to-Case	SOT89 (Note 7)	_	30	_	°C/W
	SOT223 (Note 7)	_	39	_		

Electrical Characteristics (Cont.) (@T_A = +25°C, V_{IN} = V_{OUT} +1V, C_{OUT} = 1 μ F, C_{IN} = 1 μ F, V_{EN} = 2V, unless otherwise specified.)

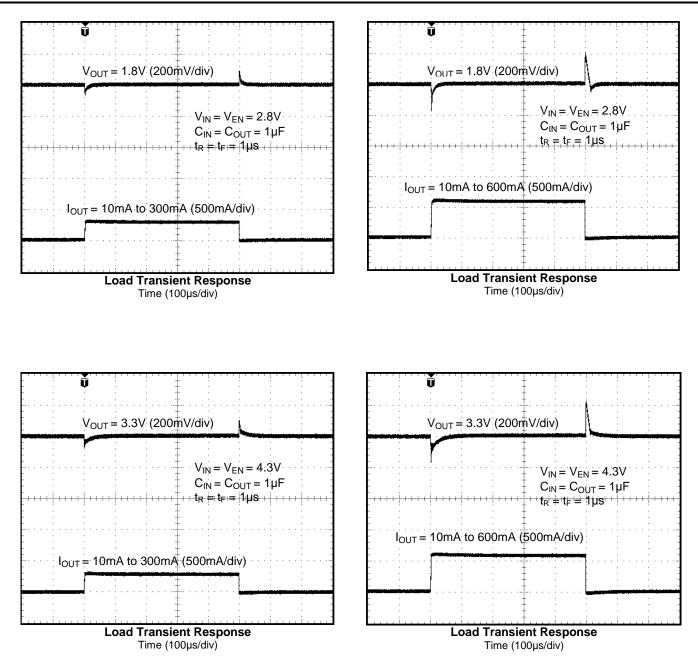
Note: 7. Test condition for all packages: Device mounted on FR-4 substrate PC board, 1oz copper, with minimum recommended pad layout.

Typical Performance Characteristics

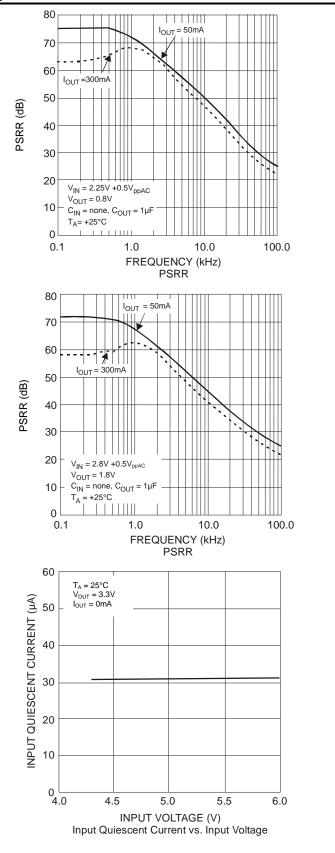


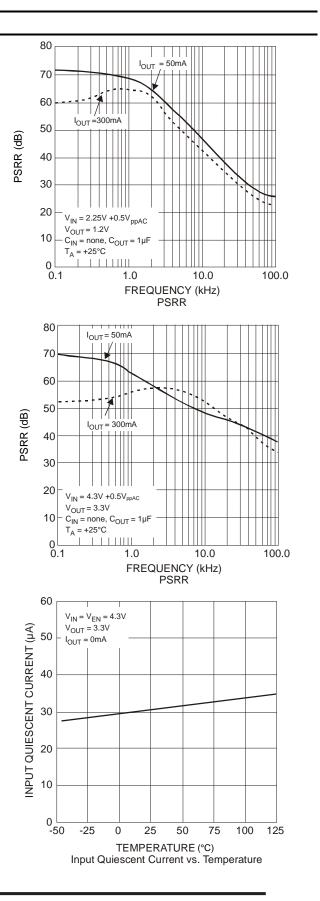


Typical Performance Characteristics (Cont.)

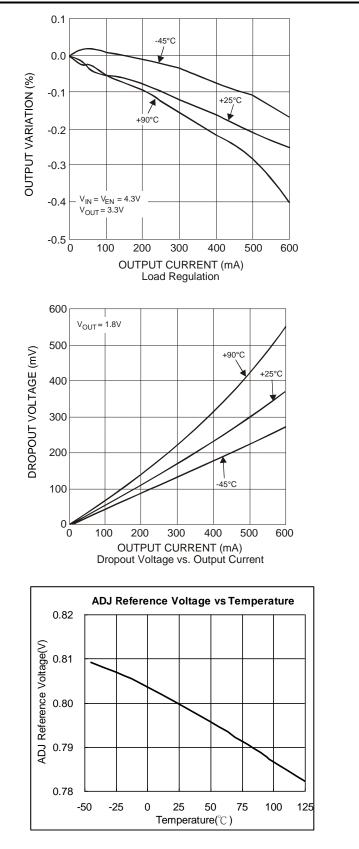


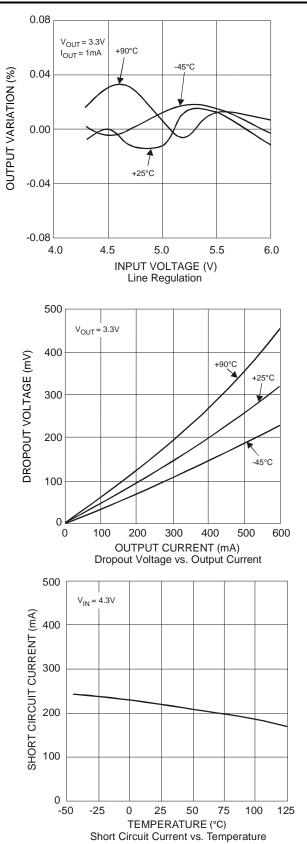






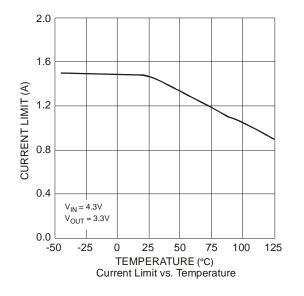








Typical Performance Characteristics (Cont.)



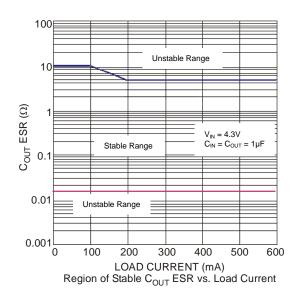
Application Information

Input Capacitor

A 1µF ceramic capacitor is recommended between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and reduce noise. For PCB layout, a wide copper trace is required for both IN and GND pins. A lower ESR capacitor type allows the use of less capacitance, while higher ESR type requires more capacitance.

Output Capacitor

The output capacitor is required to stabilize and improve the transient response of the LDO. The ZX7365 is stable with very small ceramic output capacitors. Using a ceramic capacitor value that is at least 1μ F with ESR > $15m\Omega$ on the output ensures stability. Higher capacitance values help to improve line and load transient response. The output capacitance may be increased to keep low undershoot and overshoot. Output capacitor must be placed as close as possible to OUT and GND pins.



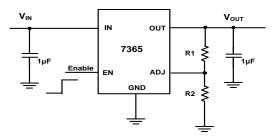




Application Information (Cont.)

Adjustable Operation

The ZX7365 provides output voltage from 0.8V to 5.0V through external resistor divider as shown below.



The output voltage is calculated by:

$$V_{OUT} = V_{REF} \left(1 + \frac{R_1}{R_2} \right)$$

Where $V_{REF} = 0.8V$ (the internal reference voltage)

Rearranging the equation will give the following that is used for adjusting the output to a particular voltage:

$$R_1 = R_2 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

To maintain the stability of the internal reference voltage, R₂ needs to be kept smaller than 80kΩ.

No Load Stability

Other than external resistor divider, no minimum load is required to keep the device stable. The device will remain stable and regulated in no load condition.

ON/OFF Input Operation

The ZX7365 is turned on by setting the EN pin high, and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under V_{IL} and V_{IH} .

Current Limit Protection

When output current at OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to approximately 1.4A to prevent overcurrent and to protect the regulator from damage due to overheating.

Short Circuit Protection

When OUT pin is short-circuit to GND, short circuit protection will be triggered and clamp the output current to approximately 240mA. This feature protects the regulator from overcurrent and damage due to overheating.

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +145°C, allowing the device to cool down. When the junction temperature reduces to approximately +130°C, the output circuitry is enabled again. Depending on power dissipation, thermal resistance and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Ultra Fast Start-Up

After enabled, the ZX7365 is able to provide full power in a s little as hundreds of microseconds, typically 200µs, without sacrificing low ground current. This feature will help load circuitry move in and out of standby mode in real time, eventually extend battery life for mobile phones and other portable devices.



Application Information (Cont.)

Fast Transient Response

Fast transient response LDO can extend battery life. TDMA-based cell phone protocols such as Global System for Mobile Communications (GSM) have a transmit/receive duty factor of only 12.5%, enabling power savings by putting much of the baseband circuitry into standby mode in between transmit cycles. In baseband circuits, the load often transitions virtually instantaneously from 100µA to 100mA. To meet this load requirement, the LDO must react very quickly without a large voltage drop or overshoot — a requirement that cannot be met with conventional, general-purpose LDO.

The 7365's fast transient response from 0 to 600mA provides stable voltage supply for fast DSP and GSM chipset with fast changing load.

Low Quiescent Current

The ZX7365, consuming only around 35µA for all input ranges, provides great power saving in portable and low power applications.

Wide Output Range

The ZX7365, with a wide output range of 0.8V to 5.0V, provides a versatile LDO solution for many portable applications.

Power Dissipation

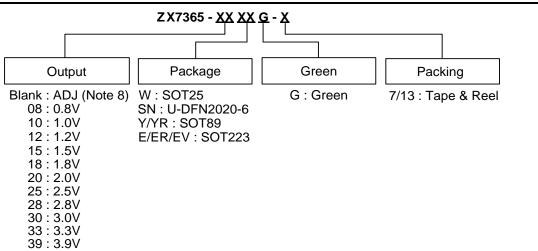
The device power dissipation and proper sizing of the thermal plane connected to the thermal pad is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

PD = (VIN - VOUT) X IOUT

The maximum power dissipation, handled by the device, depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be calculated by the equation in the following:

 $P_{D}(MAX @ T_{A}) = \frac{(+145 \circ C - T_{A})}{R_{\theta,JA}}$

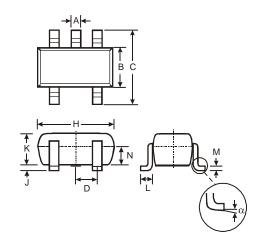
Ordering Information





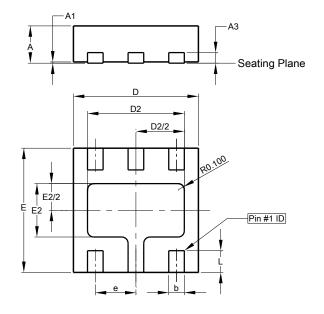
Package Outline Dimensions

(1) Package Type: SOT25



	SOT	[25	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	_	_	0.95
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
κ	1.00	1.30	1.10
L	0.35	0.55	0.40
Μ	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	
All D	imensi	ons in	mm

(2) Package Type: U-DFN2020-6

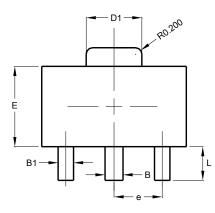


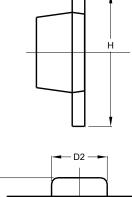
U-DFN2020-6					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.03		
A3	-	-	0.15		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.45	1.65	1.55		
е	-	-	0.65		
E	1.95	2.075	2.00		
E2	0.76	0.96	0.86		
L	0.30	0.40	0.35		
	imens	ions in	mm		





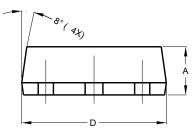
(3) Package Type: SOT89

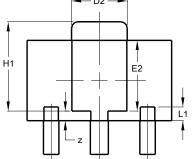




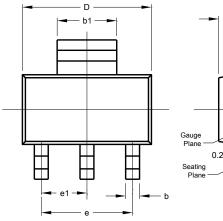
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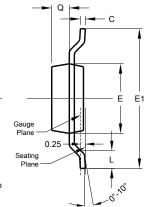
	SOT89					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
E	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
e	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	Dimens	sions in	mm			

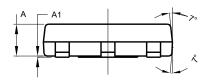




(4) Package Type: SOT223







	SOT223					
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
E	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All [Dimens	ions in	mm			

